

# LH534600

CMOS 4M (512K × 8 / 256K × 16)  
Mask-Programmable ROM

## FEATURES

- 524,288 × 8 bit organization (Byte mode)  
262,144 × 16 bit organization (Word mode)
- $\overline{\text{BYTE}}$  input pin selects bit configuration
- Access time: 100 ns (MAX.)
- Low-power consumption:  
Operating: 550 mW (MAX.)  
Standby: 1.65 mW (MAX.)
- Static operation (Internal sync. system)
- Automatic power-down mode
- TTL compatible I/O
- Three-state outputs
- Single +5 V power supply
- Packages:  
40-pin, 600-mil DIP  
40-pin, 525-mil SOP  
44-pin, 14 × 14 mm<sup>2</sup> QFP  
48-pin, 12 × 18 mm<sup>2</sup> TSOP (Type I)
- X16 word-wide pinout

## DESCRIPTION

The LH534600 is a 4M bit mask-programmable ROM with two programmable memory organizations of byte and word modes. It is fabricated using silicon-gate CMOS process technology.

## PIN CONNECTIONS

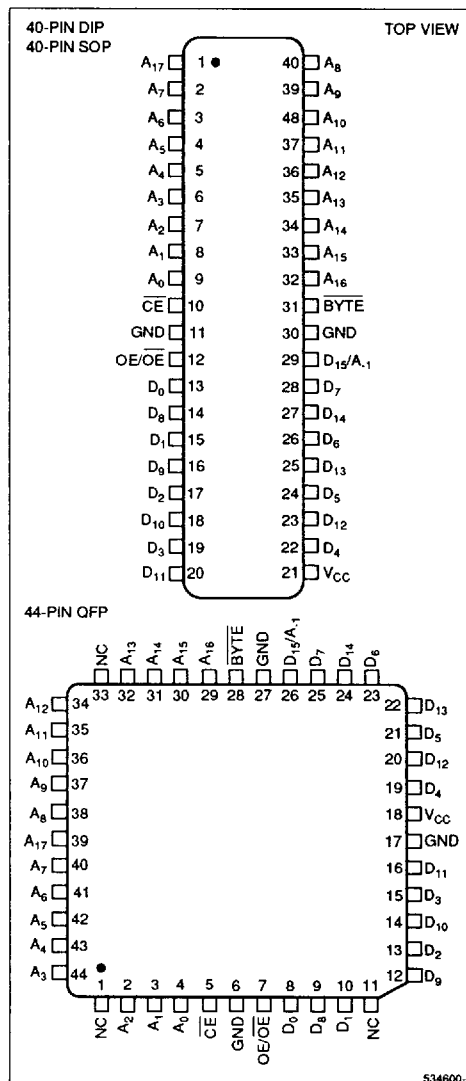
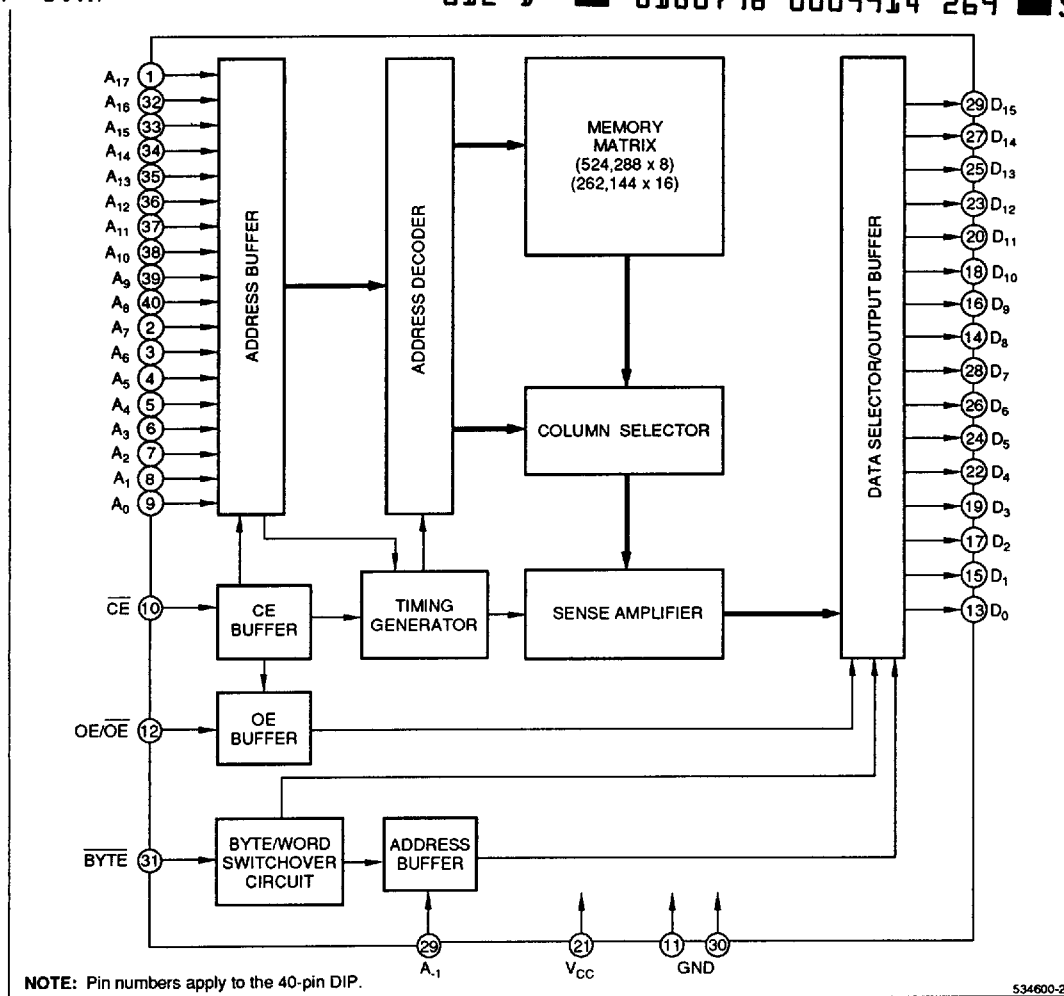


Figure 1. Pin Connections for DIP, SOP, and QFP Packages

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Figure 2. LH534600 Block Diagram

## PIN DESCRIPTION

| SIGNAL                           | PIN NAME                  | NOTE |
|----------------------------------|---------------------------|------|
| A-1                              | Address input (BYTE MODE) | 1    |
| A <sub>0</sub> - A <sub>17</sub> | Address input             |      |
| D <sub>0</sub> - D <sub>15</sub> | Data output               |      |
| CE                               | Chip Enable input         |      |

| SIGNAL          | PIN NAME            | NOTE |
|-----------------|---------------------|------|
| OE/OE           | Output Enable input | 2    |
| BYTE            | Byte/word switch    |      |
| V <sub>CC</sub> | Power supply (+5 V) |      |
| GND             | Ground              |      |

## NOTES:

1. D<sub>15</sub>/A-1 pin becomes LSB address input (A-1) when the bit configuration is set in byte mode, and data output (D<sub>15</sub>) when in word mode. BYTE input pin selects bit configuration.
2. Active level of OE/OE is mask-programmable.

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## TRUTH TABLE

| $\overline{CE}$ | $\overline{OE}$ | BYTE | A-1           | MODE         | D <sub>0</sub> - D <sub>7</sub>  | D <sub>8</sub> - D <sub>15</sub> | SUPPLY CURRENT               | NOTE |
|-----------------|-----------------|------|---------------|--------------|----------------------------------|----------------------------------|------------------------------|------|
| H               | X               | X    | X             | Non selected | High-Z                           |                                  | Standby (I <sub>SB</sub> )   | 1    |
| L               | H               | X    | X             | Non selected | High-Z                           |                                  | Operating (I <sub>CC</sub> ) |      |
| L               | L               | H    | Input inhibit | Word         | D <sub>0</sub> - D <sub>7</sub>  | D <sub>8</sub> - D <sub>15</sub> | Operating (I <sub>CC</sub> ) |      |
| L               | L               | L    | L             | Byte         | D <sub>0</sub> - D <sub>7</sub>  | High-Z                           | Operating (I <sub>CC</sub> ) |      |
| L               | L               | L    | H             | Byte         | D <sub>8</sub> - D <sub>15</sub> | High-Z                           | Operating (I <sub>CC</sub> ) |      |

## NOTE:

1. The input state of  $\overline{BYTE}$  pin must not be changed during operation. The  $\overline{BYTE}$  pin must be set to either High or Low.  
X = H or L

## ABSOLUTE MAXIMUM RATINGS

| PARAMETER             | SYMBOL           | RATING                       | UNIT | NOTE |
|-----------------------|------------------|------------------------------|------|------|
| Supply voltage        | V <sub>CC</sub>  | -0.3 to +7.0                 | V    | 1    |
| Input voltage         | V <sub>IN</sub>  | -0.3 to V <sub>CC</sub> +0.3 | V    |      |
| Output voltage        | V <sub>OUT</sub> | -0.3 to V <sub>CC</sub> +0.3 | V    |      |
| Operating temperature | T <sub>opr</sub> | 0 to +70                     | °C   |      |
| Storage temperature   | T <sub>stg</sub> | -55 to +150                  | °C   |      |

## NOTE:

1. The maximum applicable voltage on any pin with respect to GND.

RECOMMENDED OPERATING CONDITIONS (T<sub>A</sub> = 0 to +70°C)

| PARAMETER      | SYMBOL          | MIN. | TYP. | MAX. | UNIT |
|----------------|-----------------|------|------|------|------|
| Supply voltage | V <sub>CC</sub> | 4.5  | 5.0  | 5.5  | V    |

DC CHARACTERISTICS (V<sub>CC</sub> = 5 V ± 10%, T<sub>A</sub> = 0 to +70°C)

| PARAMETER              | SYMBOL           | CONDITIONS                                | MIN. | TYP. | MAX.                 | UNIT | NOTE |
|------------------------|------------------|-------------------------------------------|------|------|----------------------|------|------|
| Input 'Low' voltage    | V <sub>IL</sub>  |                                           | -0.3 |      | 0.8                  | V    |      |
| Input 'High' voltage   | V <sub>IH</sub>  |                                           | 2.2  |      | V <sub>CC</sub> +0.3 | V    |      |
| Output 'Low' voltage   | V <sub>OL</sub>  | I <sub>OL</sub> = 2.0 mA                  |      |      | 0.4                  | V    |      |
| Output 'High' voltage  | V <sub>OH</sub>  | I <sub>OH</sub> = -400 μA                 | 2.4  |      |                      | V    |      |
| Input leakage current  | I <sub>LI</sub>  | V <sub>IN</sub> = 0 V to V <sub>CC</sub>  |      |      | 10                   | μA   |      |
| Output leakage current | I <sub>LO</sub>  | V <sub>OUT</sub> = 0 V to V <sub>CC</sub> |      |      | 10                   | μA   | 1    |
| Operating current      | I <sub>CC1</sub> | t <sub>RC</sub> = 100 ns                  |      |      | 100                  | mA   | 2    |
|                        | I <sub>CC2</sub> | t <sub>RC</sub> = 1 μs                    |      |      | 70                   |      |      |
|                        | I <sub>CC3</sub> | t <sub>RC</sub> = 100 ns                  |      |      | 100                  | mA   | 3    |
|                        | I <sub>CC4</sub> | t <sub>RC</sub> = 1 μs                    |      |      | 70                   |      |      |
| Standby current        | I <sub>SB1</sub> | $\overline{CE} = V_{IH}$                  |      |      | 3                    | mA   |      |
|                        | I <sub>SB2</sub> | $\overline{CE} = V_{CC} - 0.2 V$          |      |      | 300                  | μA   |      |

## NOTES:

1.  $OE = V_{IL}$ ,  $\overline{CE}/\overline{OE} = V_{IH}$   
 2.  $V_{IN} = V_{IH}/V_{IL}$ ,  $\overline{CE} = V_{IL}$ , outputs open  
 3.  $V_{IN} = (V_{CC} - 0.2 V)$  or 0.2 V,  $\overline{CE} = 0.2 V$ , outputs open

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**AC CHARACTERISTICS** ( $V_{CC} = 5\text{ V} \pm 10\%$ ,  $T_A = 0\text{ to }+70^\circ\text{C}$ )

| PARAMETER                | SYMBOL    | LH534600 |      |      | UNIT | NOTE |
|--------------------------|-----------|----------|------|------|------|------|
|                          |           | MIN.     | TYP. | MAX. |      |      |
| Read cycle time          | $t_{RC}$  | 100      |      |      | ns   |      |
| Address access time      | $t_{AA}$  |          |      | 100  | ns   |      |
| Chip enable access time  | $t_{ACE}$ |          |      | 100  | ns   |      |
| Output enable delay time | $t_{OE}$  |          |      | 40   | ns   |      |
| Output hold time         | $t_{OH}$  | 5        |      |      | ns   |      |
| CE to output in High-Z   | $t_{CHZ}$ |          |      | 40   | ns   | 1    |
| OE to output in High-Z   | $t_{OHZ}$ |          |      | 40   | ns   |      |

**NOTE:**

1. This is the time required for the outputs to become high-impedance.

**AC TEST CONDITIONS**

| PARAMETER               | RATING         |
|-------------------------|----------------|
| Input voltage amplitude | 0.6 V to 2.4 V |
| Input rise/fall time    | 10 ns          |
| Input reference level   | 1.5 V          |
| Output reference level  | 1.5 V          |
| Output load condition   | 1TTL +100 pF   |

**CAPACITANCE** ( $V_{CC} = 5\text{ V} \pm 10\%$ ,  $f = 1\text{ MHz}$ ,  $T_A = 25^\circ\text{C}$ )

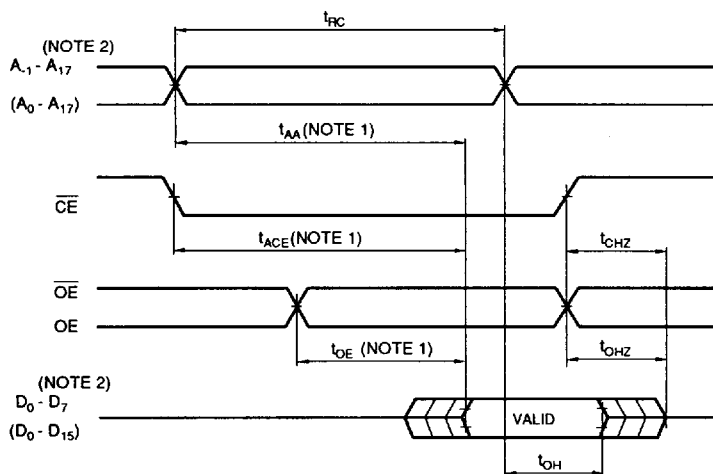
| PARAMETER          | SYMBOL    | MIN. | TYP. | MAX. | UNIT |
|--------------------|-----------|------|------|------|------|
| Input capacitance  | $C_{IN}$  |      |      | 10   | pF   |
| Output capacitance | $C_{OUT}$ |      |      | 10   | pF   |

**CAUTION**

To stabilize the power supply, it is recommended that a high-frequency bypass capacitor be connected between the  $V_{CC}$  pin and the GND pin.

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**NOTES:**

1. Data becomes valid after the intervals  $t_{AA}$ ,  $t_{ACE}$  and  $t_{OE}$  from address input and output enable input, respectively have been met.
2. Apply to byte mode. Signals in parentheses apply to word mode.

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Figure 3. Timing Diagram

## ORDERING INFORMATION

